A Guide to SPI FRAM Devices

Covers Functional Description, Timing, Pseudo Code



OVERVIEW

The SPI family of FRAM products offers the market serial high speed, low power, nonvolatile FRAM memory. SPI FRAM memory devices take advantage of FRAM's fast write performance that provides writing at bus speeds up to 25MHz without waiting for writes to complete. SPI FRAM densities start at 4 Kb (512 Byte) and extend to 512 Kb (64 KByte).

These devices employ an industry standard 4-wire SPI interface. The interface is synchronous. A clock SCK is used to latch data into and out of the device, and a chip select pin is used to enable/disable the device. Stand-alone SPI FRAM devices are designated FM25xxx. The FM24xxx part numbers designate the stand-alone 2-wire (I^2C) FRAM family.

WHY USE SPI?

The Serial Peripheral Interface (SPI) is a serial bus created by Motorola and is provided as a dedicated interface on their MCUs and those from other semiconductor suppliers, such as TI, Atmel, Microchip, Analog Devices, etc. Other processor types have an SPI port as well, e.g. DSPs and network processors. For microcontroller-based systems that require high serial data rates, the SPI interface is an ideal choice. SPI FRAM memories offer the highest speed SPI devices in Ramtron's serial memory product line. Some can transfer data up to 25Mbit/sec with as few as 3 pins. A dedicated SPI port on a microcontroller makes the choice an easy one in those cases. However, many microcontrollers do not have a dedicated SPI port, so the use of bit-banging provides a means to use general purpose I/O pins. This method involves software that controls or "bangs away" at the I/O port.



Figure 1. Basic SPI Interface

SPEED ADVANTAGES

The FRAM memory technology allows a system designer to write large data blocks much faster than EEPROM equivalents. The SPI interface operates up to 25MHz but not only clock speed but FRAM memories do not impose write delays on the system. FRAM writes each data byte immediately following the 8th bit in each byte received. That is, FRAM devices do not use a page buffer, which is used on all EEPROMs and Serial flash memories. Those devices use it to temporarily store write data, which is then written to the EEPROM/flash array within a 5 to 10ms period. The combination of no write delays and high clock speed makes the FRAM compelling for any application that needs to write a lot of data quickly. The system designer has complete freedom over how many bytes to write to the SPI FRAM. When you write a byte or two in random locations in a FRAM, the write cycle time is approximately 1µs, whereas an EEPROM imposes its 5 to 10ms write cycle on you. Also there are no worries about page buffer sizes that change when your system requires the next memory density a few years later.



The chart below shows the time required to write a 256Kb array - FRAM vs. EEPROM. Even for an EEPROM with a 64-byte page buffer, the FRAM device is orders of magnitude faster at the same clock rate. This is especially significant on a production line where there is a limited time to program system settings.



Figure 2. Write Time to Fill a 256Kb SPI Memory Array

Note that the time to write a 256Kb EEPROM memory is not improved much by increasing the clock frequency from 5MHz to 25MHz. The long write delay needed for each page write dominates.

THE SPI BUS

All transactions occur with /CS low while address, control, and data are serially clocked into the device in byte-size blocks. Address, control, and data-in are clocked in on the SI pin, and data-out is clocked out on the SO pin. "Op-codes" provide control over the device. Read and write transactions follow the sequence: op-code, address, data. Other transactions that do not involve a data transfer are used to set/clear the WEL bit in the Status Register. The Status Register holds memory write-protect settings. For EEPROM-based SPI memories, the Status Register also holds an important bit called /RDY. It is the ready flag that tells the SPI controller if a write cycle has completed or not. EEPROMs typically require 5 to 10ms of delay before the device can be accessed after a write. With FRAM, there are no delays, no waiting for the internal write to complete. The controller can read and write the memory like a true RAM. There are no write delays and no page buffer limitations to constrain the user.

There are six op-codes that control all SPI FRAM devices. Each op-code is an 8-bit command that instructs the memory or Status Register to do something. There is only one op-code for each active /CS cycle.

Name	Op-Code	Address	Data	Action						
WREN	0000_0110b	-	-	Sets WEL						
WRITE	0000_0010b	2-byte*	Memory Data in	Writes data to FRAM array if WEL=1. When /CS goes high, WEL is cleared.						
READ	0000_0011b	2-byte*	Memory Data out	Reads data from FRAM array						
WRDI	0000_0100b	-	-	Clears WEL						
RDSR	0000_0101b	-	St Reg data out	Read WPEN, BP(1:0), WEL bits						
WRSR	0000_0001b	-	St Reg data in	Write WPEN and BP(1:0) bits						

Table	1.	Descri	ntion	of Oi	o-Codes
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* Note that some devices use 1-byte and upper address bit(s) in the op-code. See Addressing an SPI FRAM for details.

SYSTEM HOOKUP

Multiple devices may be used as long as the controller has extra pins to drive a chip select to each FRAM device.



Figure 3. System Configuration for Two FRAM Devices

For a microcontroller that has no dedicated SPI bus, a general purpose port may be used. Figure 4 shows this configuration. Bit-banging code drives this interface.



Figure 4. System Configuration for μ C using GPIO – Single FRAM

STAND-ALONE SPI FRAM PRODUCTS

The following table summarizes the basic characteristics of the stand-alone SPI FRAM products. Most 3.3V devices are specified to operate over a 2.7 to 3.6V range and the 5V devices operate over a 4.5 to 5.5V. The FM25256 operates down to 4.0V.

Table 2. SPI FRAM Product Lineup

	3.3V				5V				
	FM25L04	FM25L16	FM25CL64	FM25L256	FM25L512	FM25040A	FM25C160	FM25640	FM25256
Density	4Kb	16Kb	64Kb	256Kb	512Kb	4Kb	16Kb	64Kb	256Kb
Organized Internally	512x8	2Kx8	8Kx8	32Kx8	64Kx8	512x8	2Kx8	8Kx8	32Kx8
Number of Addr bits	9	11	13	15	16	9	11	13	15
Number of Addr bytes	1	2	2	2	2	1	2	2	2
Max. Clock Freq.	14MHz	18MHz	20MHz	25MHz	20MHz	20MHz	20MHz	5MHz	15MHz
Supported Clock	0, 3	0, 3	0, 3	0, 3	0, 3	0, 3	0, 3	0, 3	0, 3
Modes									
Package	DFN8	DFN8	DFN8	DFN8	DFN8	SOIC8	SOIC8	SOIC8	SOIC8
	SOIC8	SOIC8	SOIC8	SOIC8					

READ/WRITE TRANSACTIONS

The SPI interface is synchronous to a clock that is driven by the controller. All SPI devices that Ramtron builds will register data input on the rising edge of SCK and drive data back to the controller on the falling edge of SCK. To comply with this timing, controllers generally drive signals to the memory on the falling edge of SCK so that the signals have time to propagate and satisfy the setup timing specifications of the memory device.

Memory Reads

Format: READ op-code, MSB Address, LSB Address, Data-out, (Data-out, Data-out, ...)

A read cycle is straightforward. The controller issues a READ op-code and address, then data comes out on the SO pin, e.g. data-out(0), data-out(1), data-out(2), etc. The /CS pin must remain low throughout the cycle. Once /CS is deasserted high, data output stops and SO goes to a hi-Z state. The clocked-in address is the starting address of the first data byte. Subsequent data bytes may be accessed simply by keeping /CS low while clocking-out data byte after data byte, each byte being read from an address incremented by the SPI FRAM device.



Memory Writes:

Format: WREN op-code, WRITE op-code, MSB Address, LSB Address, Data-in, (Data-in, Data-in, ...)

A write cycle requires the controller to issue two op-codes, WREN and WRITE, in the following sequence. Each op-code must be bounded by /CS low. WREN op-code, WRITE op-code, address, data-in(0), data-in(1), data-in(2), etc. The clocked-in address is the starting address of the first data byte. Subsequent data bytes may be written by keeping /CS low while clocking-in data byte after data byte, each byte being written to an address incremented by the SPI FRAM device. Each data byte is written to the FRAM array on the 8th clock edge of that byte. There are no page buffers or write delays.

Note that the WEL bit in the Status Register is internally set and cleared by the SPI FRAM device. It is set after clocking-in the WREN op-code and is cleared on the rising edge of /CS at the end of a write operation. Reading the Status Register using the RDSR op-code between the WREN and WRITE op-codes will not clear the WEL bit. Some users read the Status Register immediately following the WREN to check that the WEL bit is set. However, reading the WEL bit is not necessary to complete the write operation.

A complete single-byte write transaction is shown in Figure 6.

	WEL bit is set here	Rising /CS edge clears the WEL bit
/CS		
SCK		
SI	WREN opcode WRITE op-code	MSB Address LSB Address Data In
SO		



<u>Status Register Write:</u> Format: WREN op-code, WRSR op-code, Data-in

Writing the Status Register allows the user to 1) write-protect memory blocks and 2) enable the /WP pin. There are two block protect bits BP1 and BP0. They provide upper quarter, upper half, or entire array protection against writes. Once the BP(1:0) bits are written, the states are retained even after chip power is removed. WPEN enables or disables the external /WP pin. Software may be used to override the /WP pin from system tampering. WEL is a read-only bit that simply tells the user if the Write Enable Latch has been set, which allows writes to either the Status Register or the memory.







Status Register Read: Format: RDSR op-code, Data-out

Reading the Status Register allows the user to view the state of the WPEN bit, the BP(1:0) write-protect bits, and the WEL bit.



Figure 7. Read Status Register Timing

ADDRESSING AN SPI FRAM

Stand-alone SPI FRAM devices require a 1-byte or 2-byte address, depending on the density. Following the op-code, a starting address is shifted-in MSB first. Immediately following the least significant address byte (LSB), data-in is expected from the master for writes and data-out is driven by the memory for reads. As long as SCK continues to toggle, the internal address is automatically incremented and data in/out continues until /CS is deasserted.

Note that the 4Kb devices (and obsolete parts) require only one byte of address.



Figure 8. Addressing Differs between Densities

CLOCKING MODES

The FM25xxx families support two of the four clocking modes: Mode 0 and Mode 3. Some of Ramtron's early SPI parts support only Mode 0. Note that independent of the mode, all Ramtron parts clock data into the device on the rising SCK edge and clock data out on the falling edge of SCK. The difference between Modes 0 and 3 is simply whether SCK starts low or high when /CS is asserted low.

	Mode 0	Mode 1	Mode 2	Mode 3			
SCK Starts	Low	Low	High	High			
SI Data-In Latched on	\uparrow	\downarrow	\downarrow	\uparrow			
SO Data-Out Driven from	\downarrow	\uparrow	\uparrow	\downarrow			

Ramtron FRAM devices support Modes 0 and 3.

HALF-DUPLEX OPERATION

To reduce pincount on an SPI interface, the data lines can be tied together to create a common data I/O line. This 3-wire interface is SPI's minimum pincount configuration. The controller must now ensure that the SIO line is hi-Z during read cycles. A secondary issue is that since the data bus is now half-duplex, this potentially reduces the data bandwidth.



Figure 9. True 3-Wire SPI Interface

In this configuration, the data line is bi-directional and the controller must be able to hi-Z the data line when the memory device is driving read data back to the host. Bus contention will otherwise occur. Regardless of the timing mode (0 or 3), all SPI FRAMs latch data-in on the rising edge of SCK and drive data-out on the falling edge of SCK.



Figure 10. Common Data I/O Line and Bus Turnaround

WRITE PROTECTION

SPI FRAM devices may be write-protected using the /WP hardware pin or programming Status Register bits. The Status Register itself may be protected in addition to the FRAM memory array. The Status Register contains nonvolatile Block Protect bits BP(1:0) to disable writes to portions of the memory array. The BP bits are colored yellow to indicate they are nonvolatile. There is also a nonvolatile bit called WPEN which enables the /WP hardware pin. Bit location 0 is reserved as a /RDY bit for EEPROM and serial flash. This bit is used in these devices so that the user can determine whether or not the memory is ready for another command by reading the Status Register. The /RDY bit is internally hardwired low in all SPI FRAM devices since the chip is always ready after a write cycle.

A Write Protection table is provided in every SPI FRAM datasheet. It covers all the cases for write protecting the Status Register and the FRAM array. Here's a summary of the table:

- FRAM array is protected by BP bit(s) high, even if WPEN=0 and /WP pin=1
- FRAM array is not protected when BP bit(s) low, even if WPEN=1 and /WP pin=0
- Status Register is protected only when WPEN=1 and /WP pin=0
- Since the FM25040A and FM25L04 do not have a WPEN bit, all writes (memory array and Status Register) are blocked when /WP pin=0

Status Register									
7	6	5	4	3	2	1	0		
WPEN	0	0	0	BP1	BP0	WEL	0		

Figure	11. Status	Register	and Block	Protect	Settings
8					

POWER CYCLING

A FRAM device is a high speed non-volatile memory and if it is active during a power ramp up or ramp down, there is the possibility of overwriting array data. Care must be taken in controlling signals during power cycle events. It is important to understand the device might inadvertently write data at mid-level power supply levels when chip select is active (low), for example.

SPI FRAM devices have no power management circuits other than a simple internal power-on reset circuit. It is the user's responsibility to ensure that V_{DD} is within datasheet tolerances to prevent incorrect operation. It is recommended that the V_{DD} power supply voltage ramp up and ramp down in a well-controlled manner. Switch-mode power supplies are notorious for uncontrolled outputs as they power-up or power-down. It is also recommended that the device is powered down with chip select inactive (high). The system designer should be aware of chip-enable and V_{DD} states during power cycles. Please refer to application note, AN302 – SPI Reads/Writes and Data Protection During Power Cycles. It describes the internal memory operations and offers some system design suggestions to avoid data corruption. It can be found on the Ramtron web site.



Pseudo Code Examples

#define WREN 0x06 #define WRITE 0x02 #define READ 0x03 #define RDSR 0x05 #define WRSR 0x01 #define WRDI 0x04 In every case below, the parentheses designate the /CS pin going low "(" and high ")". /***** Memory Write (single byte to location 0F30h) ******/ WREN (0x06)// Sets WEL bit. WREN must precede WRITE opcode. WRITE (0x02, // 0x02 is WRITE opcode // starting address MSB 0x0F, // starting address LSB 0x30, 0x55)// 0x55 is data written to location 0F30h /***** Memory Write (multiple bytes to starting location 07FC) ******/ // Sets WEL bit. WREN must precede WRITE opcode. WREN (0x06)WRITE (0x02, // 0x02 is WRITE opcode // starting address MSB 0x07, 0xFC, // starting address LSB 0x55, // 0x55 is data written to location 07FCh 0xAA, // 0xAA is data written to location 07FDh // 0x55 is data written to location 07FEh 0x55, (AAx0 // 0xAA is data written to location 07FFh /***** Memory Read (single byte from location 0F31h) ******/ // 0x03 is READ opcode READ (0x03,0x0F, // starting address MSB 0x31, // starting address LSB // OxAA is data read from location OF31h 0xAA) /***** Memory Read (multiple bytes from starting location 07FCh) ******/ READ (0x03,// 0x03 is READ opcode 0x07, // starting address MSB // starting address LSB 0xFC, // 0x55 is data read from location 07FCh 0x55, // 0xAA is data read from location 07FDh 0xAA, // 0x55 is data read from location 07FEh 0x55, // 0xAA is data read from location 07FFh 0xAA) /***** Write Status Register (write protect upper half of memory) ******/ WREN (0x06)// Sets WEL bit. WREN must precede WRITE opcode. WRSR (0x01, // 0x01 is WRSR opcode // 0x08 sets the BP1 bit which protects the upper 0×08 // half of the memory array. /***** Read Status Register ******/ // Sets WEL bit. WREN must precede WRITE opcode. WREN (0x06)WRSR (0x01, // 0x01 is WRSR opcode 0x08// 0x08 sets the BP1 bit which protects the upper // half of the memory array.

NOTE: Text in **BLUE** indicates data being sent by the controller. Text in **RED** indicates data being received by the controller.